# NSN 5962-01-178-2777

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## **Body Length:**

1.290 inches

### Body Width:

Between 0.500 inches and 0.610 inches

#### **Body Height:**

Between 0.150 inches and 0.210 inches

# **Maximum Power Dissipation Rating:**

1.0 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

Paveway iii Illgb

#### Features Provided:

Electrostatic sensitive and programmed and monolithic and w/active pull-up and 3-state output

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

### **Output Logic Form:**

Transistor-transistor logic

#### Current Rating Per Characteristic:

185.00 milliamperes reverse current, dc absolute and 100.00 milliamperes reverse current, dc

#### **Product Name:**

Microcircuit, digital programed operational flight prom

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source and -1.5 volts input and 5.5 volts input

#### Time Rating Per Chacteristic:

100.00 nanoseconds access

#### Memory Device Type:

Prom

#### **Memory Capacity:**

2k x 8

#### **Special Features:**

This programed microcircuit is made from pn m38510/21002bja and programed iaw drw 2793858 cage 96214

#### **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

A458a0

